Very Low Leakage Trench-based Schottky Rectifier

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These are Pb–Free Devices

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR–ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

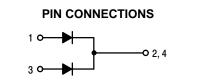
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec

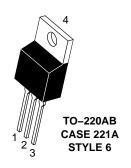


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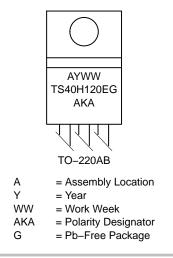
www.onsemi.com

VERY LOW LEAKAGE, SCHOTTKY BARRIER RECTIFIERS 40 AMPERES, 120 VOLTS





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	120	V
Average Rectified Forward Current (Rated V_R , $T_C = 124^{\circ}C$) (Rated V_R , $T_C = 134^{\circ}C$)	Per device Per diode	I _{F(AV)}	40 20	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, $T_C = 120^{\circ}C$) (Rated V _R , Square Wave, 20 kHz, $T_C = 130^{\circ}C$)	Per device Per diode	I _{FRM}	80 40	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	250	A
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dV/dt	36	V/ns

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Rating	Symbol	NTST40H120ECTG	Unit
Maximum Thermal Resistance per Device Junction-to-Case Junction-to-Ambient	000	0.81 70	°C/W °C/W

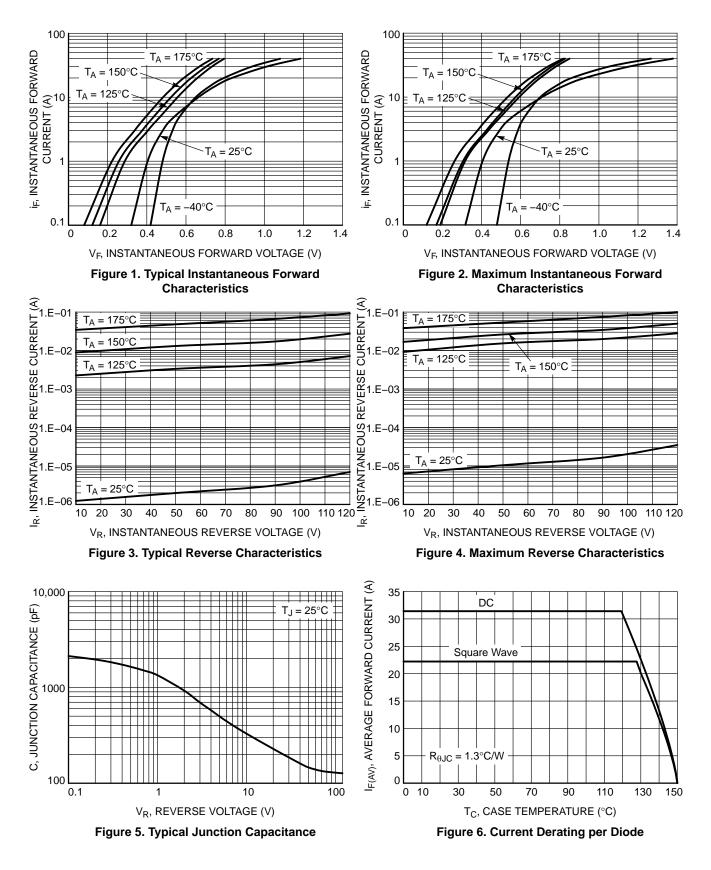
ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
	VF	0.54 0.67 0.84	_ _ 0.93	V
$(I_F = 5 A, T_J = 125^{\circ}C)$ $(I_F = 10 A, T_J = 125^{\circ}C)$ $(I_F = 20 A, T_J = 125^{\circ}C)$		0.47 0.56 0.66	- - 0.7	
Maximum Instantaneous Reverse Current (Note 1) $(V_R = 90 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_R = 90 \text{ V}, T_J = 125^{\circ}\text{C})$	۱ _R	3 5		μA mA
(Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)		- 7	25 28	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

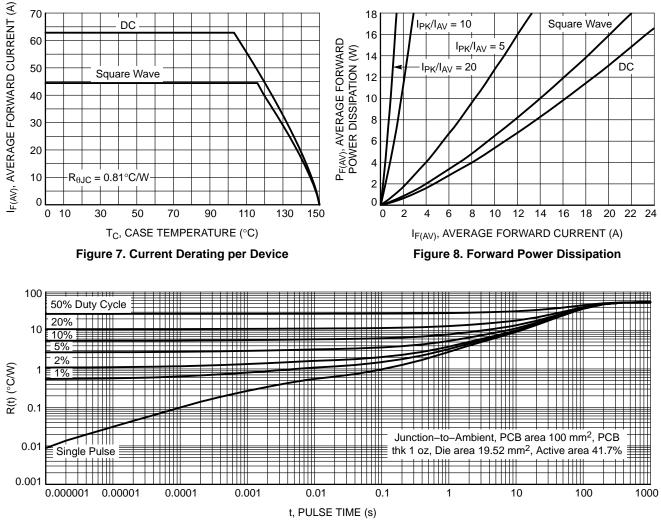


Figure 9. Thermal Characteristics

ORDERING INFORMATION

Device	Package	Shipping
NTST40H120ECTG	TO-220AB (Pb-Free)	50 Units / Rail

onsemi

SCALE 1:1		TO-22 CASE 22 ISSUE	21A AK SEATING PLANE	2. Cont 3. dimen Leai	ROLLING D NSION Z DE D IRREGUL/	AND TOLERAI IMENSION: IN FINES A ZONI ARITIES ARE A F102 DEVICE	ICHES E WHERE AL ALLOWED.	ANSI Y14.5№	
				4. MAX V	WIDTH FOR	F102 DEVICE	= 1.3510101		
	I	Γ I			INC	HES	MILLIM	ETERS	
				DIM	MIN.	MAX.	MIN.	MAX.	
	2 3			А	0.570	0.620	14.48	15.75	
<u> </u>	┟┰┟┟╌┙──┼			В	0.380	0.415	9.66	10.53	
⊢	₩+₩++			С	0.160	0.190	4.07	4.83	
	í lí	f I		D	0.025	0.038	0.64	0.96	
' z –	I I K			F	0.142	0.161	3.60	4.09	
	î î			G	0.095	0.105	2.42	2.66	
				н	0.110	0.161	2.80	4.10	
	¥ ₩	ü l		J	0.014	0.024	0.36	0.61	
V —	R —			ĸ	0.500	0.562	12.70 1.15	14.27	
G	J-	╼║╼		N	0.045	0.060	4.83	1.52 5.33	
Ŭ,	' → → D			Q	0.190	0.210	2.54	3.04	
_	N -			R	0.100	0.120	2.54	2.79	
				s	0.030	0.055	1.15	1.41	
				т	0.235	0.255	5.97	6.47	
				U U	0.000	0.050	0.00	1.27	
				v	0.045		1.15		
				z		0.080		2.04	
2. 3. 4. STYLE 5: PIN 1. 2. 3. 4. STYLE 9: PIN 1. 2. 3.	BASE PIN 1. COLLECTOR 2. EMITTER 3. COLLECTOR 4. GATE PIN 1. DRAIN 2. SOURCE 3. DRAIN 2. GATE PIN 1. CALL STYLE 10 GATE PIN 1. COLLECTOR 2. EMITTER 3.	BASE EMITTER COLLECTOR EMITTER ANODE CATHODE CATHODE CATHODE	2. 3. 4. STYLE 7: PIN 1. 2. 3. 4. STYLE 11: PIN 1. 2. 3.		E E	2. MA 3. GA 4. MA STYLE 8: PIN 1. CA 2. AN 3. EX 4. AN STYLE 12: PIN 1. MA 2. MA 3. GA	IN TERMINAL THODE DDE TERNAL TRIP DDE IN TERMINAL IN TERMINAL	2 2 /DELAY .2	

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